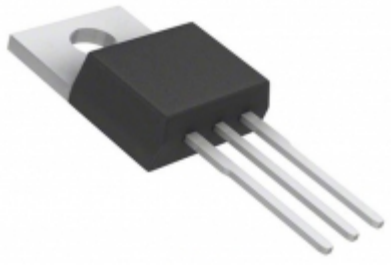

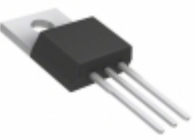
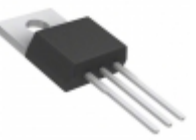

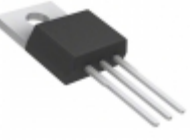
 	<h2 style="color: red;">FQP19N20L</h2>
	<p>Hersteller-Teilenummer: FQP19N20L</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 200V 21A TO-220</p> <p>Datenblätter: 1.FQP19N20L.pdf 2.FQP19N20L.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 38500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="text-align: center;">YIC International Co., Limited.</p>	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP19N20L
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 21A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	38500 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	140W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	21A (Tc)
Rds On (Max) @ Id, Vgs	140 mOhm @ 10.5A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	35nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	2200pF @ 25V
Verpackung	Tube

FQP19N20L ist neu im Original, Suche FQP19N20L Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP19N20L Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP19N20L: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP19N20L AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 21A TO-220</p>	 <p>FQP19N20C_F080 Fairchild/ON Semiconductor MOSFET N-CH 200V 19A TO-220</p>	 <p>FQP19N20CTSTU AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19A TO-220</p>	 <p>FQP1N60 AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 1.2A TO-220</p>
 <p>FQP1N60C VB FQP1N60C VB</p>	 <p>FQP19N20C_F080 AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19A TO-220</p>	 <p>FQP1N60 Fairchild/ON Semiconductor MOSFET N-CH 600V 1.2A TO-220</p>	 <p>FQP1N50 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 1.4A TO-220</p>

heiße Teile

Mehr

FQP16N25C	FQP16N25C	FQP17N08	FQP17N08	FQP17N08L
FQP17N08L	FQP17N40	FQP17N40	FQP17P06	FQP17P06
FQP17P10	FQP17P10	FQP18N20V2	FQP18N20V2	FQP18N50V2
FQP18N50V2	FQP19N10	FQP19N10	FQP19N10L	FQP19N10L
FQP19N20	FQP19N20	FQP19N20C	FQP19N20C	FQP19N20L
FQP1N60C	FQP20N06	FQP20N06	FQP20N06L	FQP20N06L
FQP20N06TSTU	FQP20N06TSTU	FQP20N60	FQP22N30	FQP22N30
FQP22P10	FQP22P10	FQP24N08	FQP24N08	FQP24N40
FQP27N25	FQP27N25	FQP27N60	FQP27P06	FQP27P06
FQP2N60B	FQP2N60C	FQP2N60C	FQP2N65C	FQP30N06

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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